

Transistors as a switch

Session 6b for Electronics and
Telecommunications
A Fairfield University E-Course
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Module: Semiconductor Electronics

(in two parts)

- Text: “Electronics,” Harry Kybett, Wiley, 1986, ISBN 0-471-00916-4
- References:
 - [Electronics Tutorial](#) (Thanks to Alex Pounds)
 - [Electronics Tutorial](#) (Thanks to Mark Sokos)
- 5 - Semiconductors, Diodes and Bipolar Transistors
 - 5 on-line sessions plus one lab
- 6 - FETs, SCRs, Other Devices and Amplifiers
 - 5 on-line sessions plus one lab
- Mastery Test part 3 follows this Module

Section 6: FETs, SCRs, Other Devices and Operational Amplifiers

- **OBJECTIVES:** This section reviews additional important semiconductor devices and their applications. The Operational Amplifier is also studied.

Section 6 Schedule:

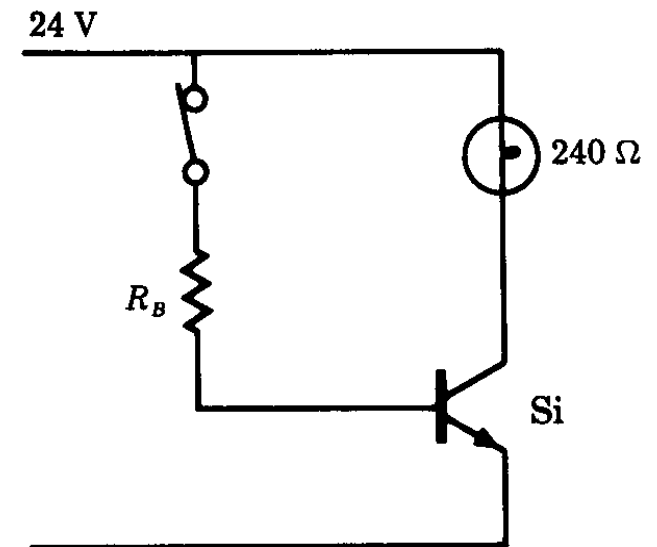
Session 6a	01/15	Field Effect Transistors	Kybett pp 70 – 77, pp 201-209
Session 6b	01/20	Transistors as a switch	Kybett pp 78 –107
Session 6c	01/22	SCR's, Triacs and UJTs	
Session 6c (Lab - 02/01, Sat.)	01/27	Class "A", "B", and "C" Amplifiers	
Session 6e	02/05	Op-Amps	Kybett pp 209-215
Session 6f (Quiz 6 due 02/23)	02/10	Review for Quiz 6	
Session 6g	02/24	Discuss Quiz 6	
Session 6h	02/26	Review for MT3	
MT3	03/02	MT3 Exam	
Session 6i	03/10	Discuss MT3	

FET Summary

- A voltage-controlled resistor
- Channel material
 - N-channel FET
 - P-channel FET
- FET types
 - Junction FET (JFET)
 - Metal Oxide Gate FET (MOSFET)
 - Complementary Symmetry MOSFET (CMOS)
- Simple high input impedance amplifiers
- Very effective as switches (Session 6b)

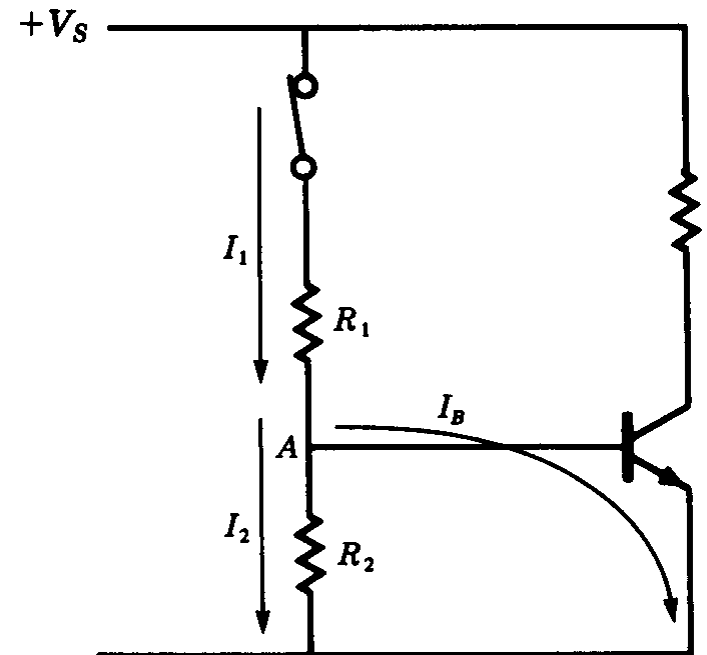
An NPN Switch

- Open switch – no current
- Closed switch – base current flows
 - For saturation (fully on)
 $I_c \sim 0.1$ amp
 - If $\beta = 100$, $I_b \sim 1$ milliamp



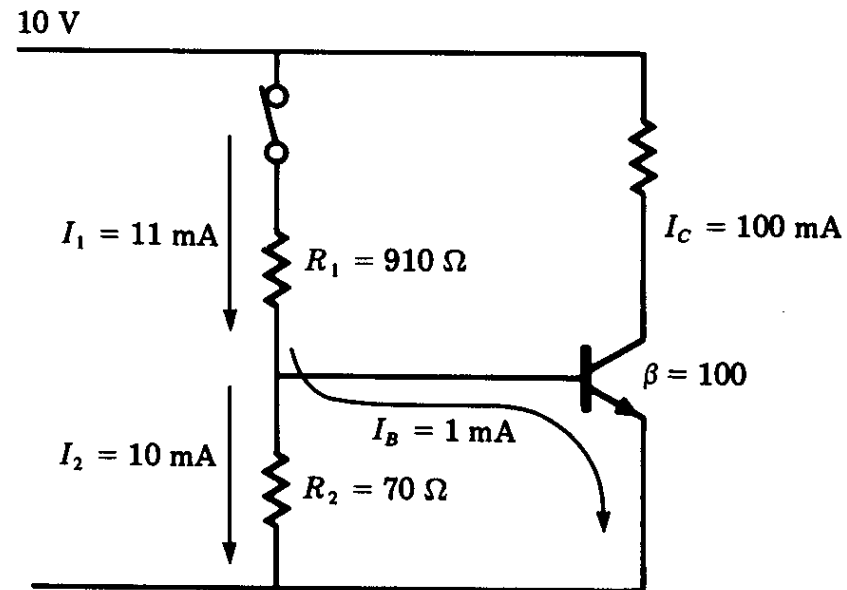
Better Biasing

- **Never** leave transistor (or IC) inputs dangling
 - Noise sensitivity
 - Static discharge failures
- Reduced leakage current sensitivity
 - I_{cb} : reverse leakage current
 - R_2 conducts leakage current to ground



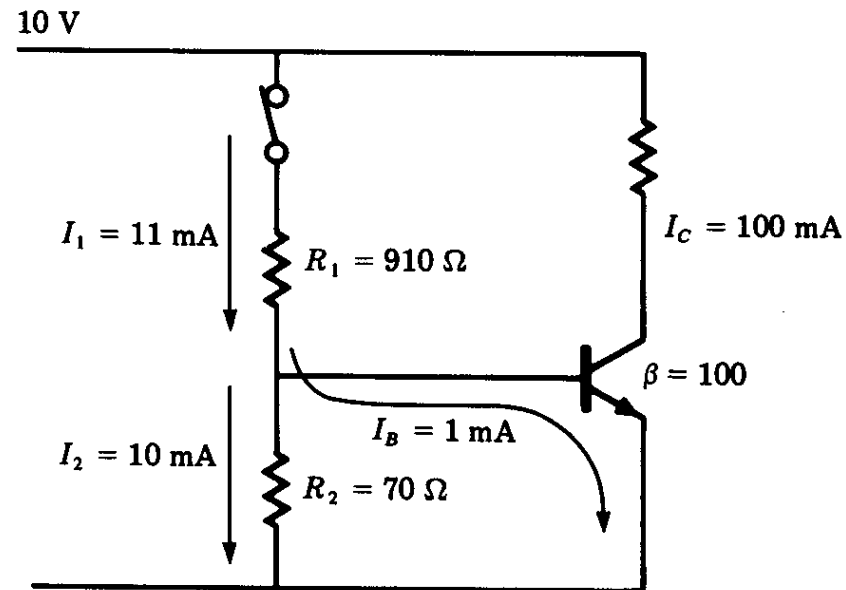
Biassing Analysis

- Desire 100 ma load current



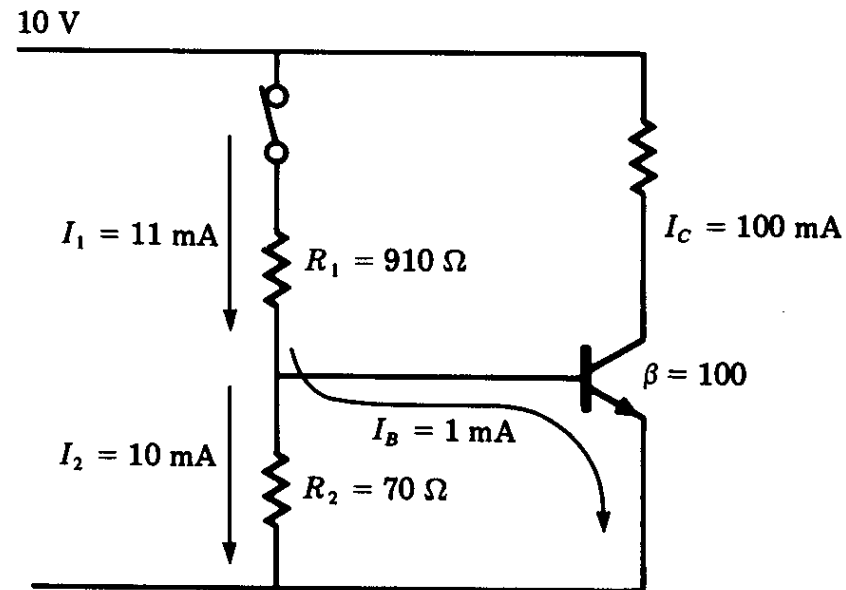
Biasing Analysis

- Desire 100 ma load current
- Base current >1 ma for saturation ($\beta=100$)



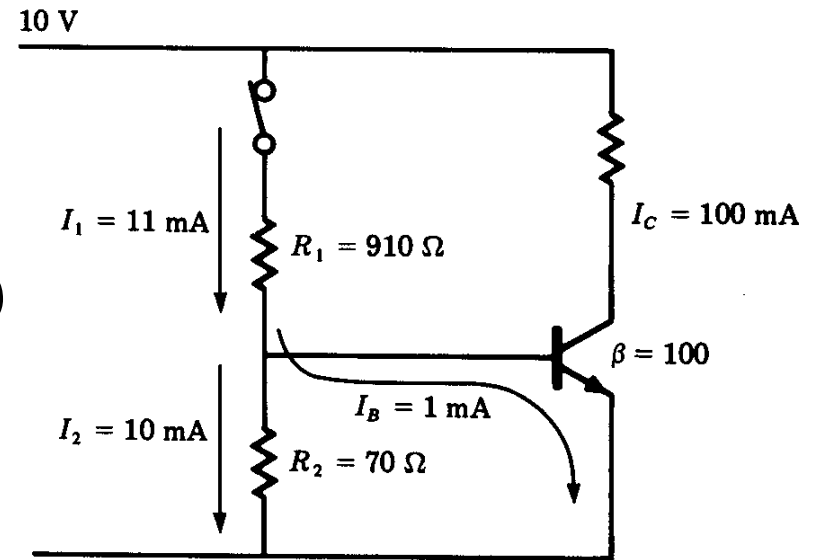
Biasing Analysis

- Desire 100 ma load current
- Base current >1 ma for saturation ($\beta=100$)
- Set $I_2 = 10$ ma
 - Low impedance biasing for reduced leakage sensitivity



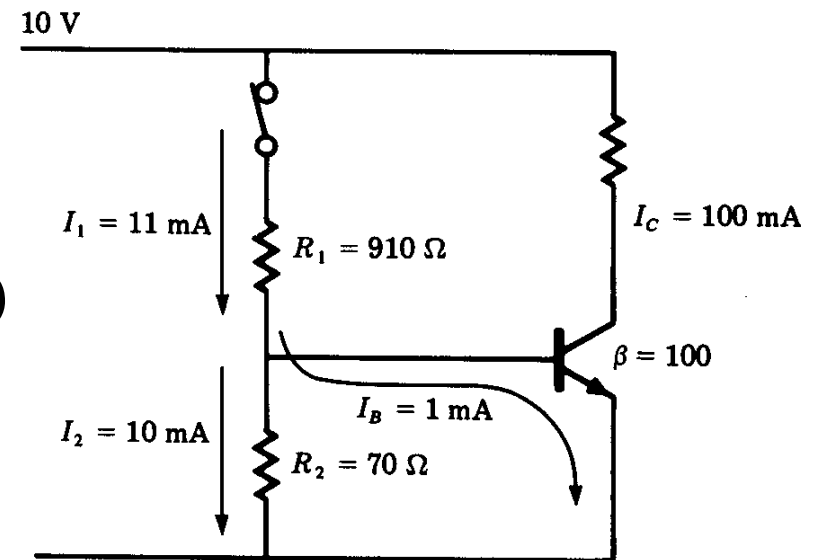
Biasing Analysis

- Desire 100 ma load current
- Base current >1 ma for saturation ($\beta=100$)
- Set $I_2 = 10$ ma
- $R_2 = 70 \Omega$ (68 Ω)
(Low impedance biasing;
reduced leakage sensitivity)



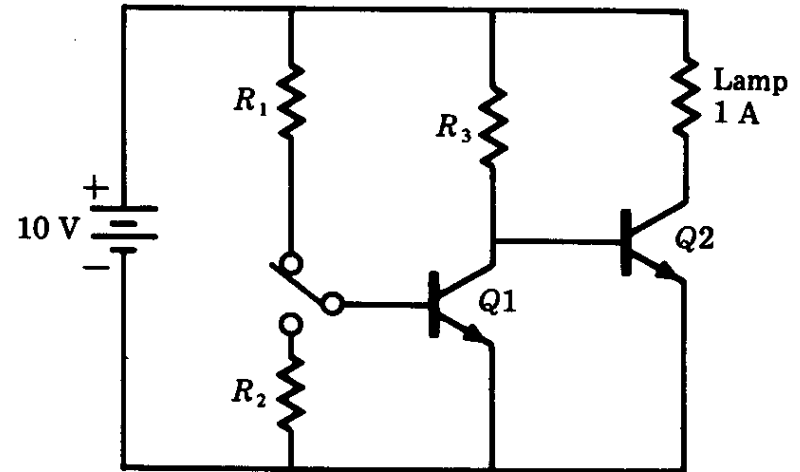
Biasing Analysis

- Desire 100 ma load current
- Base current >1 ma for saturation ($\beta=100$)
- Set $I_2 = 10$ ma
- $R_2 = 70 \Omega$ (68 Ω)
(Low impedance biasing;
reduced leakage sensitivity)
- $R_1 = 846 \Omega$ (820 Ω)
- Note reduced current gain
and higher power use



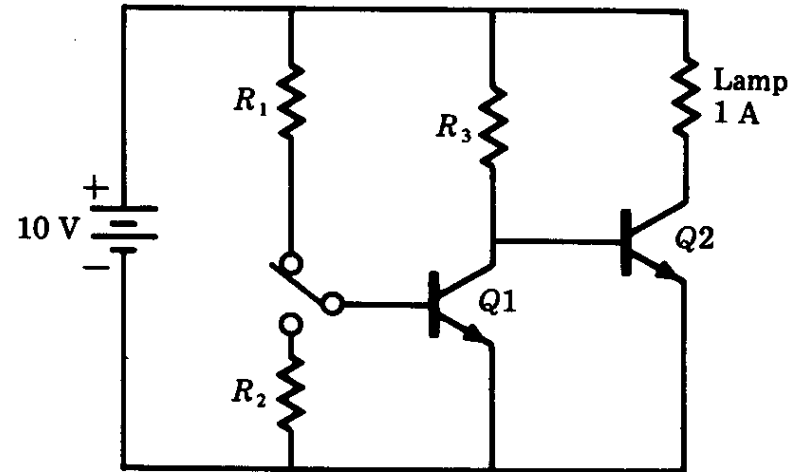
More Current Gain

- Cascade two transistors
- Bias the first transistor for a smaller load current
- The second transistor provides the higher current
- Is the lamp on or off here?



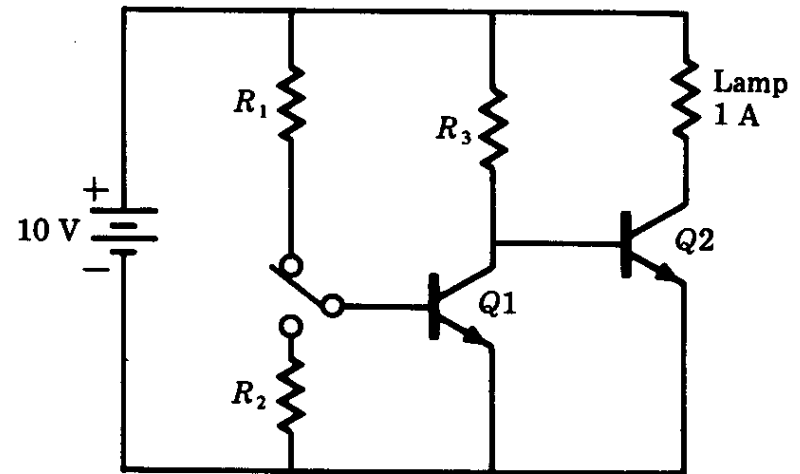
More Current Gain

- Cascade two transistors
- Bias the first transistor for a smaller load current
- The second transistor provides the higher current
- Is the lamp on or off here?
 - Q1 is on



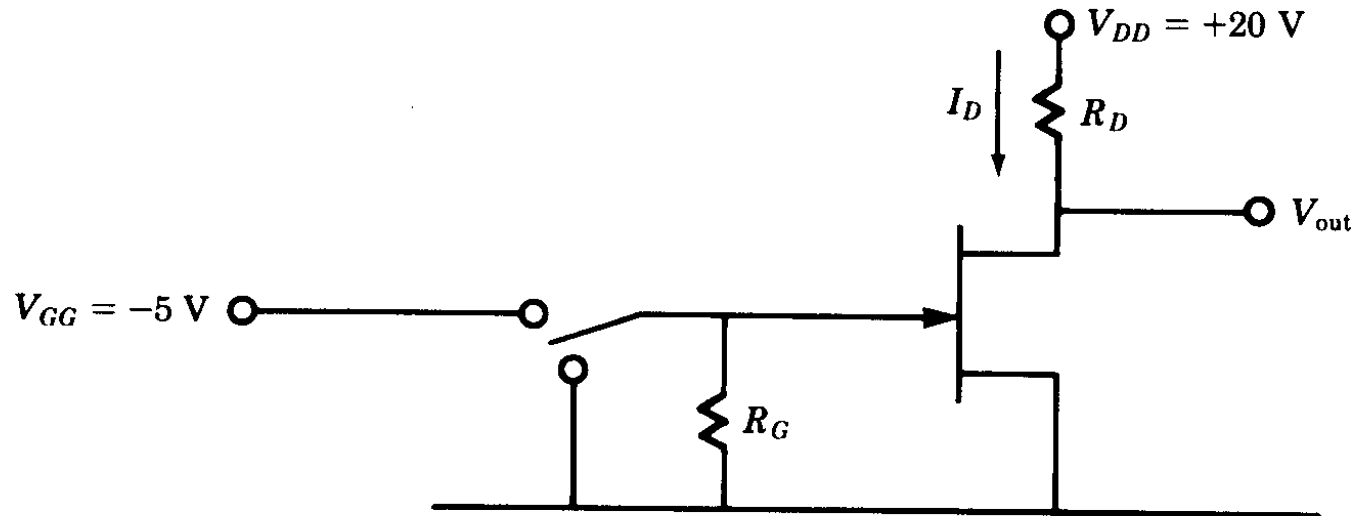
More Current Gain

- Cascade two transistors
- Bias the first transistor for a smaller load current
- The second transistor provides the higher current
- Is the lamp on or off here?
 - Q1 is on
 - Q2 is off



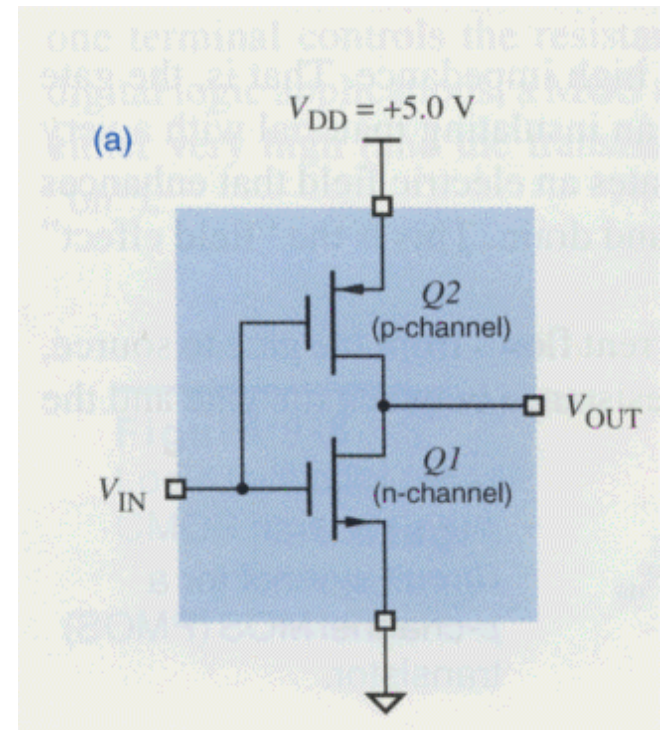
An N-Channel JFET Switch

- $V_{gg} = 0$; the JFET is on
- $V_{gg} = -5$; the JFET is off



A CMOS Inverter

- Q1: N-channel MOSFET, Q2: P-channel MOSFET
- If V_{in} is grounded
 - Q1 is off and Q2 is on
 - V_{out} is +5v
- If V_{in} is +5 volts
 - Q2 is off and Q1 is on
 - V_{out} is 0 volts
- Q1 and Q2 are FET switches (always opposite condition)



Note: these MOSFETs are designed to be off for $V_{gs} < 1 \text{ volt}$

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